

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









Important notice

Dear Customer,

On 7 February 2017 the former NXP Standard Product business became a new company with the tradename **Nexperia**. Nexperia is an industry leading supplier of Discrete, Logic and PowerMOS semiconductors with its focus on the automotive, industrial, computing, consumer and wearable application markets

In data sheets and application notes which still contain NXP or Philips Semiconductors references, use the references to Nexperia, as shown below.

Instead of http://www.nxp.com, http://www.nxp.com, http://www.nexperia.com, http://www.nexperia.com)

Instead of sales.addresses@www.nxp.com or sales.addresses@www.semiconductors.philips.com, use salesaddresses@nexperia.com (email)

Replace the copyright notice at the bottom of each page or elsewhere in the document, depending on the version, as shown below:

- © NXP N.V. (year). All rights reserved or © Koninklijke Philips Electronics N.V. (year). All rights reserved

Should be replaced with:

- © Nexperia B.V. (year). All rights reserved.

If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

PMEG6002EB; PMEG6002TV

0.2 A very low V_F MEGA Schottky barrier rectifiers

Rev. 01 — 24 November 2006

Produ

Product data sheet

Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifiers with an integrated guard ring for stress protection, encapsulated in ultra small and flat lead Surface-Mounted Device (SMD) plastic packages.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
PMEG6002EB	SOD523	SC-79	single
PMEG6002TV	SOT666	-	dual isolated

1.2 Features

Forward current: I_F ≤ 0.2 A

Reverse voltage: V_R ≤ 60 V

Very low forward voltage

Ultra small and flat lead SMD plastic packages

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diode						
l _F	forward current	T _{amb} ≤ 25 °C	-	-	0.2	Α
V_R	reverse voltage		-	-	60	V
V_{F}	forward voltage	$I_F = 200 \text{ mA}$	<u>[1]</u> _	540	600	mV

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



2. Pinning information

Table 3. Pinning

Table 3.	Pinning		
Pin	Description	Simplified outline	Symbol
SOD523			
1	cathode	[1]	. 84 -
2	anode	1 2	1
SOT666			
1	anode (diode 1)		
2	not connected	6 5 4	6 5 4
3	cathode (diode 2)		
4	anode (diode 2)		
5	not connected		1 2 3 <i>006aaa440</i>
6	cathode (diode 1)	1 2 3	

^[1] The marking bar indicates the cathode.

3. Ordering information

Table 4. Ordering information

Type number	Package			
	Name	Description	Version	
PMEG6002EB	SC-79	plastic surface-mounted package; 2 leads	SOD523	
PMEG6002TV	-	plastic surface-mounted package; 6 leads	SOT666	

4. Marking

Table 5. Marking codes

Type number	Marking code
PMEG6002EB	B2
PMEG6002TV	1B

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per diode	•				
V _R	reverse voltage		-	60	V
l _F	forward current	$T_{amb} \le 25 ^{\circ}C$	-	0.2	Α
I _{FRM}	repetitive peak forward current	$\begin{array}{l} t_p \leq 1 \text{ ms;} \\ \delta \leq 0.25 \end{array}$	-	2	Α
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	[1] -	2.5	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	PMEG6002EB		<u>[1]</u> -	300	mW
	PMEG6002TV		<u>[1]</u> -	200	mW
			[2] _	300	mW
Per devic	е				
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
	PMEG6002TV		<u>[1]</u> -	300	mW
			[2] _	400	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

Table 7. Thermal characteristics

Table 1.	Thermal Characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per device)						
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air					
	PMEG6002EB		[1][2]	-	-	400	K/W
	PMEG6002TV		[1][2]	-	-	416	K/W
			[1][3]	-	-	318	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[4]				
	PMEG6002EB			-	-	75	K/W
	PMEG6002TV			-	-	195	K/W

^[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_B are a significant part of the total power losses.

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

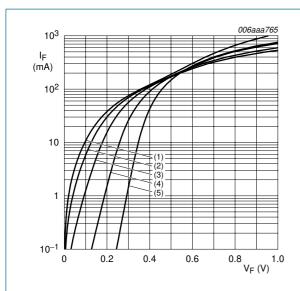
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per diod	е					
V _F	forward voltage		<u>[1]</u>			
		I _F = 0.1 mA	-	130	170	mV
		I _F = 1 mA	-	190	230	mV
		I _F = 10 mA	-	260	300	mV
		I _F = 100 mA	-	420	470	mV
		$I_F = 200 \text{ mA}$	-	540	600	mV
I_R	reverse current					
		V _R = 10 V	-	2	10	μΑ
		V _R = 60 V	-	20	100	μΑ
		V _R = 10 V; T _{amb} = 100 °C	-	310	-	μΑ
C _d	diode capacitance	$V_R = 1 V; f = 1 MHz$	-	14	20	pF

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

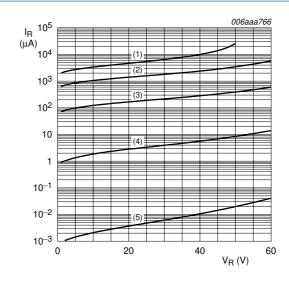
^[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

^[4] Soldering point of cathode tab.



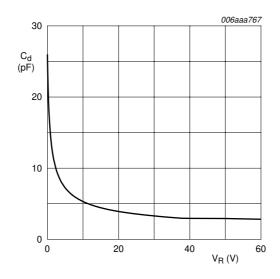
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

Forward current as a function of forward Fig 1. voltage; typical values



- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 125 \, ^{\circ}C$
- (3) $T_{amb} = 85 \, ^{\circ}C$
- (4) $T_{amb} = 25 \, ^{\circ}C$
- (5) $T_{amb} = -40 \, ^{\circ}C$

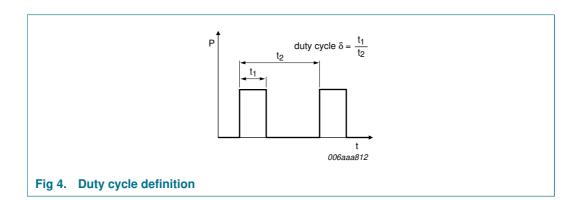
Fig 2. Reverse current as a function of reverse voltage; typical values



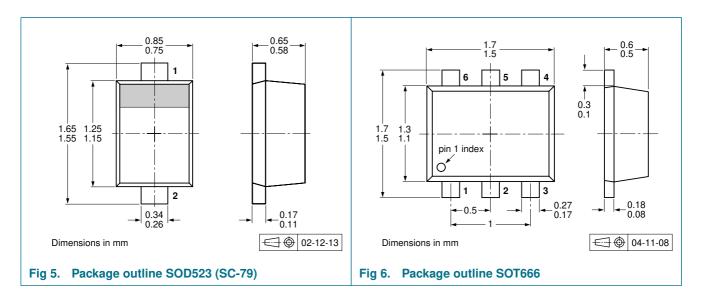
 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$

Fig 3. Diode capacitance as a function of reverse voltage; typical values

8. Test information



9. Package outline



10. Packing information

Table 9. Packing methods

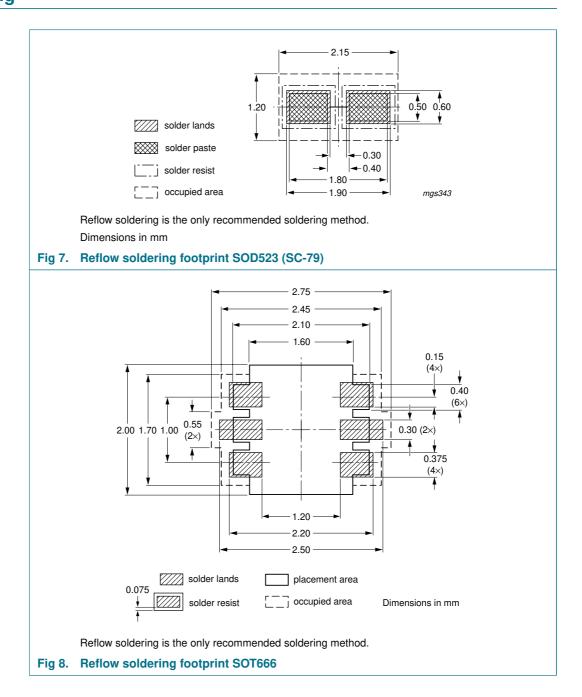
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number Package		Description	Packing quantity				
			3000	4000	8000	10000	
PMEG6002EB	SOD523	2 mm pitch, 8 mm tape and reel	·-	-	-315	-	
		4 mm pitch, 8 mm tape and reel	-115	-	-	-135	
PMEG6002TV SOT666		2 mm pitch, 8 mm tape and reel	-	-	-315	-	
		4 mm pitch, 8 mm tape and reel	-	-115	-	-	

^[1] For further information and the availability of packing methods, see $\underline{\text{Section 14}}$.

PMEG6002EB_PMEG6002TV_1 © NXP B.V. 2006. All rights reserved.

11. Soldering



PMEG6002EB; PMEG6002TV

0.2 A very low V_F MEGA Schottky barrier rectifiers

12. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG6002EB_PMEG6002TV_1	20061124	Product data sheet	-	-

PMEG6002EB_PMEG6002TV_1 © NXP B.V. 2006. All rights reserved. Rev. 01 — 24 November 2006

PMEG6002EB; PMEG6002TV

0.2 A very low V_F MEGA Schottky barrier rectifiers

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

13.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

13.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

13.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

14. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: salesaddresses@nxp.com

PMEG6002EB_PMEG6002TV_1 © NXP B.V. 2006. All rights reserved.

NXP Semiconductors

PMEG6002EB; PMEG6002TV

0.2 A very low V_F MEGA Schottky barrier rectifiers

15. Contents

1	Product profile 1
1.1	General description
1.2	Features
1.3	Applications
1.4	Quick reference data
2	Pinning information
3	Ordering information
4	Marking
5	Limiting values
6	Thermal characteristics 4
7	Characteristics 4
8	Test information 6
9	Package outline 6
10	Packing information 6
11	Soldering 7
12	Revision history 8
13	Legal information 9
13.1	Data sheet status 9
13.2	Definitions9
13.3	Disclaimers
13.4	Trademarks9
14	Contact information 9
15	Contents 10

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

